

PATENT APPLICATION

Docket No.:D490

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Title: Integrated Glass Ceramic Systems

SPECIFICATION

Statement of Government Interest

The invention was made with Government support under
contract No. F04701-00-C-0009 by the Department of the Air
Force. The Government has certain rights in the invention,

Reference to Related Application

The present application is related to applicant's copending
application entitled Glass Ceramic Spacecraft S/N: xx/xxx,xxx,
filed yy/yy/yy, by the same inventors.

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Field of the Invention

The invention relates to the fields of industrial art for making glass and ceramic components, tool and die arts for making molded glass and ceramic components, photostructurable arts for laser milling glass and ceramic components, semiconductor arts for fabricating semiconductors and hybrids, and for depositing conductor traces in an electrical communications grid, microelectromechanical arts for making active and passive MEMS devices, wafer flip and bond art for encapsulating electrical devices, MEMS devices, and optical devices, electrical arts for making batteries, power converters, and RF antennae, electronic arts for making processors, electronic components, optoelectronic interfaces, RF transmitters, RF receivers, and despreading correlators, electromechanical arts for making active gyros, and accelerometers, photonic arts for making optical transceivers, optical detectors, mirrors, splitters, reflectors, polarizers, lenses, and optical fibers for communicating and processing optical signals for use in an optical communications grid, all for use and incorporation into a new field of integrated glass ceramic systems having structural elements formed from molded and patterned glass ceramic materials with internally communicated optical and electrical signals while also having encapsulated electronic, photonic, electrical and microelectromechanical system devices intercommunicating through an internal electrooptical communications grid.

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Background of the Invention

There are a vast variety of conventional fabrication methods and devices used from a variety of operational systems. As examples, industrial arts have been used for making glass and ceramic components. The tool and die arts have been used for making molded glass and ceramic components. Molded components include poured, injected and stamped glass ceramic components. The semiconductor arts have been used for fabricating semiconductors, chips, and hybrids. During fabrication, depositing conductor traces and with feedthroughs are used to form an electrical communications grid about the semiconductor components. The microelectromechanical systems (MEMS) arts have been used for making active and passive MEMS sensors and actuators, among others devices. The wafer flip and bond arts have been used for electrically connecting and encapsulating electrical devices, MEMS devices, and optical devices within flip-bonded semiconductor and ceramic substrates. The electrical arts have been used for making batteries, power converters, communications processors, and RF antennae, among others. The electronic arts have been used for making power supplies, electronic devices, optoelectronic devices, RF transmitters, RF receivers, and despreading correlators, among others. The electromechanical arts have been used for making active gyros, and accelerometers, among others. The photonic arts for have been used for making optical transceivers, optical detectors, mirrors, splitters, reflectors, polarizers, lens, and optical fibers, among others,

1 for communicating and processing optical signals for use in an
2 optical communications grid. While there is a vast array of
3 technologies available, system integration of various
4 technology is limited due to operational compatibility and
5 fabrication feasibility.

6
7 One example of an intertechnology integrated system is a
8 conventional satellite. A satellite can be made of silicon for
9 exploiting strength, high thermal conductivity, infrared
10 transparency, and radiation-shielding properties of silicon
11 along with established silicon microelectronics and
12 microelectromechanical systems fabrication techniques to create
13 satellites composed of silicon components. Silicon is an
14 excellent choice as the main material for a spacecraft, but
15 bulk mechanical, thermal, and optical properties cannot be
16 significantly modified.

17
18 Glass materials have an amorphous state that is a
19 noncrystalline state. Ceramic materials have a crystalline
20 state. Ceramic materials are tougher than glass but also tend
21 to be more brittle than the glass, and hence not generally
22 suitable as a support structure in high tensile stress
23 application. Glass is weaker than ceramic, and susceptible to
24 breakage during wide temperature operating range variations,
25 but glass has superior optical transmission characteristics and
26 can be brittle. Ceramics can withstand higher temperatures than
27 the glass, but have poor optical transmission characteristics.
28 Glass and ceramic materials differ in material properties, such

1 optical transmission, electrical conductivity, thermal
2 conductivity, and chemical resistance, offering operational
3 incompatibility, and unsuitability for common use in a given
4 application. Glass materials have been annealed to reduce
5 internal stresses and prevent cracking and breakage during
6 cooling, especially for thick components. This is typically
7 accomplished by heating glass to its softening temperature,
8 followed by a slow cool-down process. Annealing decreases the
9 overall strength of glass, but also makes the glass less
10 brittle. Ceramic materials can also be annealed, but it is
11 usually used to improve strength. Ceramic annealing changes
12 crystal grain size. Glass materials have been tempered to
13 increase internal compressive stresses for increasing the
14 strength of the glass to external tensile loads. This is
15 typically accomplished by heating glass to its softening
16 temperature, followed by a rapid cool-down process. Ceramic
17 materials are not tempered.

18
19 Glass ceramic materials have portions in the amorphous
20 state and portions in the crystalline state. Glass ceramic
21 materials incorporate an in-situ nucleation process that
22 results in the crystallization of the amorphous glass phase.
23 This conversion process is nominally called devitrification.
24 Typically, glass stock is produced with additional ingredients
25 that upon heating above a specified temperature, induces
26 ceramization of the material. The bake method provides a
27 material that is controllably devitrified, that is, a
28 controlled in situ precipitation of crystalline material within

1 an amorphous glass body. Beyond the known advantages of glass
2 and ceramics, glass ceramic materials offer cost-effective
3 manufacturing of shaped ceramic parts. The initial material in
4 the glass phase is melted and molded into the desired shape and
5 then converted to the crystalline ceramic state. Because the
6 resulting material is not 100% crystalline, but a composite of
7 amorphous and crystalline phases, it is less brittle than true
8 crystalline ceramics. Glass ceramic materials are used in a
9 wide range of applications from specialized optics to consumer
10 cookware. Some well-known trade names are Macor which is
11 machinable ceramic Corning Corporation, Dicor which is a
12 biomaterial from Corning Corporation, Zerodur which is an
13 expansion material from Schott Corporation, ML-05 which is a
14 magnetic material from Nippon Electric Glass Company, and
15 Pyroceram which is a cookware material from Corning Ware.

16
17 A special category of sensitized glass ceramic material is
18 the photostructurable glass ceramic materials, also called
19 photosittals and photocerams. Photostructurable glass ceramic
20 materials differ from most glass ceramic materials in that
21 photosensitive agents are incorporated into the raw material.
22 Upon photo excitation, these agents initiate a reaction that
23 can lead to nucleation and crystallization, that is,
24 ceramization, of the glass during a controlled bake process.
25 One set of bake cycles leads to the formation of a metastable
26 crystalline state which is soluble in hydrofluoric acid (HF).
27 Another set of bake cycles leads to the formation of a stable
28 crystalline state that is resistant to etching by both acids

1 and bases. Photostructurable glass ceramic materials can be
2 photolithographically patterned, and upon baking, only those
3 patterned areas would be converted to one of the ceramic
4 states. The exposure process is typically done using a flood-
5 fill light source through an opaque mask resting directly on
6 top of the photostructurable glass ceramic material. Patterning
7 of the photostructurable glass ceramic material can be done by
8 creating the metastable state and etching away this state in
9 HF. An additional flood exposure and bake to the stable
10 crystalline state will result in a patterned ceramic component.
11 One example of a photostructurable glass ceramic material is
12 Foturan of Schott Glass Works, Mainz, Germany that requires
13 ultraviolet light for photoexposure and baking to temperatures
14 above 500C.

15
16 Photostructurable glass ceramic materials can also be
17 patterned using lasers that selectively expose parts of the
18 material. Photostructurable glass ceramic materials can be
19 micromachined with three-dimensional precision as an optically
20 patterned component by direct-write laser milling, direct-write
21 laser exposure followed by a chemical etching step to remove
22 exposed volumes, or by photolithographic patterning followed by
23 a chemical etching step to remove patterned areas.

24
25 The photostructurable glass ceramic material can be used
26 to make components for various applications. For example,
27 photostructurable glass ceramic materials have been used as a
28 substrate and structure component in a multi-thruster

1 propulsion system for a spacecraft also having metallic
2 structural components with coupled semiconductor electronics on
3 printed circuit boards. The propellant tank, propellant feed
4 lines, and thrusters are all composed of micromachined
5 photostructurable glass ceramic material, while the remaining
6 components include batteries, electromagnetic solenoid valves,
7 the pressure and temperature sensors, the fill and drain
8 valves, and the electronics. The glass ceramic thruster
9 substrate is supported in a metallic support structure
10 providing structural support for the spacecraft. One problem
11 associated with conventional metallic support structure is the
12 mix of various supporting components and their various
13 differences in thermal expansion coefficients, thermal
14 conductivity, and optical properties that need to be considered
15 over the operational temperature ranges. In addition, silicon
16 and metallic support structures require the use of harnesses
17 and cables to route electrical lines about the spacecraft. In
18 addition, silicon and metallic support structures block visible
19 optical transmission, limiting optical communications paths
20 about the silicon or metallic support structures. Further,
21 silicon and metallic support structures have different material
22 strengths rendering portions providing uneven structural
23 strength about the support structure. Further still, silicon
24 and metallic support structures have limited molding and
25 precise patterning manufacturing methods. These and other
26 disadvantages are solved or reduced using the invention.

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Summary of the Invention

An object of the invention is to provide an integrated glass ceramic system having mixed glass ceramic components being molded and patterned glass and ceramic components for providing a variety of structural shapes.

Another object of the invention is to provide an integrated ceramic system having a support structure consisting of glass and ceramic components.

Yet another object of the invention is to provide an integrated glass ceramic system having glass ceramic composite components with tempered and untempered glass portions for providing enhanced structural strength.

Still another object of the invention is to provide an integrated glass ceramic system having a plurality of glass ceramic support structures integrated together for supporting an electrical and electronic communications grid.

A further object of the invention is to provide an integrated glass ceramic system having a plurality of glass ceramic support structures that are transmissive to various optical wavelengths for providing an optical communications grid.

1 Yet A further object of the invention is to provide an
2 integrated glass ceramic system having a plurality of glass
3 ceramic support structures that are transmissive to various
4 wavelengths for providing an internal optical communications
5 grid and for supporting an internal electrical and electronic
6 communications grid combined as an electrooptical
7 communications grid that includes structured glass sensors and
8 actuators.

9
10 The invention is directed to integrated glass ceramic
11 systems, in the general form, having patterned glass ceramic
12 components having tempered and untempered portions within
13 composite components, which when integrated together, form a
14 glass ceramic support structure supporting an electrooptical
15 communications grid while encapsulating and supporting
16 operational components, such as photonic, electronic,
17 electrical, and microelectromechanical (MEMS) devices. The
18 direct-write glass ceramics components can be laser-milled,
19 laser exposed and etched, or photolithographically illuminated
20 and etched glass ceramic components. In a preferred form, an
21 integrated glass ceramic system is a glass ceramic spacecraft
22 having a plurality of molded and patterned components
23 integrated together for forming a support structure through and
24 on which is supported the electrooptical communications grid.

25
26 The unique attributes of photostructurable glass ceramic
27 materials include adapting the material for high transparency
28 in the visible through the near IR wavelengths, designing the

1 material for multifunctionality by locally altering a physical
2 property, and by processing the material for patterned
3 metallization. These attributes permit a wide range of
4 functions that can serve the structural, thermal, electrical,
5 and optical requirements of an integrated glass ceramic system.
6 By selectively controlling the material processing, the
7 photostructurable glass ceramic materials can simultaneously
8 function as support structures, thermal control systems,
9 radiation shields, optical conduits, multichip substrates,
10 photonic supports, electronics supports, antenna supports,
11 sensor structure, sensor support, actuator structure, actuator
12 support, and microelectromechanical systems supports. This
13 multifunctionality allows an entire integrated glass ceramic
14 system to be substantially fabricated from a single material
15 while supporting a plurality of integrated photonic,
16 electronic, electrical, and MEMS devices. These capabilities
17 offer predetermined consistent material strength, optical
18 properties, electrical properties, thermal properties, and
19 chemical properties. Composite ceramic structures can be
20 fabricated through localized ceramization down to the micron
21 scale. The photostructurable glass ceramic materials can have a
22 glass phase that can be used for visible through near infrared
23 optics passing wavelengths typically between 0.35 μm to 2.8 μm .
24 Photostructurable glass formulations can be designed to enhance
25 or extend these wavelength ranges. The photostructurable glass
26 ceramic materials can be manufactured using molding and
27 patterning methods to any dimension and to any shape.

28

1 The glass state in photostructurable glass ceramic
2 materials can be tempered for improved strength by using a
3 rapid cool-down process after baking. Another way to increase
4 tensile strength is by selective exposure to light with
5 subsequent baking to create crystalline domains in the glass.
6 The crystalline domains in this composite material are stronger
7 than the glass and their decreased density, compared to the
8 glass state, generates a local compressive stress.

9
10 Glass ceramic materials include sensitized glass,
11 thermally-tempered glass having increased internal stress for
12 increased strength, crystal-tempered glass ceramic composites
13 for increased strength, annealed glass having decreased
14 internal stresses and smooth surface for enabling system
15 integration, and ceramics having crystalline states made from
16 sensitized amorphous glass. Glass and ceramics can have
17 increased tempering in areas where high mechanical strength is
18 desired, and can have reduced tempering in areas where
19 mechanical or vibration compliance is desired or where a
20 clearer optical path is desired or properties are desired that
21 are more commensurate of the glass state of the original glass
22 formulation. Ceramics can withstand higher temperatures and
23 stresses than glass. A composite glass ceramic material can
24 also be thermally-tempered to provide a more uniform stress
25 response to a given load for improved mechanical toughness.

26
27 Photostructurable glass ceramic materials can be used to
28 make spacecraft support structure, insulated circuit

1 substrates, multichip module supports, actuators, sensors, and
2 thermal control systems providing simultaneous
3 multifunctionality. Almost all of the dry mass of a spacecraft,
4 except for batteries and propellant, for example, can be
5 composed of photostructurable glass and ceramic materials
6 supporting operational photonic, electronic, electrical and
7 MEMS devices. In the glass state, photostructurable glass and
8 ceramic materials can be molded into any shape using low cost
9 forming techniques, micromachined or macromachined to micron
10 tolerances, metalized for forming an electronics communications
11 grid, and then assembled into an integrated glass ceramic
12 system through fusion bonding. The multifunctional properties
13 of the photostructurable glass and ceramic materials and
14 available low cost fabrication techniques enable
15 photostructurable glass and ceramic materials to be used as a
16 support structure in low-cost reproducible satellites. When
17 tempered, the photostructurable glass and ceramic materials
18 have substantially increased reliability against tension-
19 induced fracture. Localized tempering can provide additional
20 strength in a support structure where additional support
21 strength is desirable. Tempered photostructurable glass and
22 ceramic materials are electrical insulators, thermal
23 insulators, and are transparent to visible through near IR
24 light in the glass and glass ceramic composite phases.

25
26 That is, the photostructurable glass ceramic materials can
27 be molded and patterned into any shape and composition,
28 resulting in a wide range of structural, thermal, electrical,

1 and optical properties. This multifunctionality allows almost
2 an entire integrated spacecraft to be fabricated from
3 photostructurable glass ceramic material. The photostructurable
4 glass ceramic materials are amenable to material handling
5 requirements found during conventional manufacturing. The
6 photostructurable glass ceramic materials do not outgas
7 chemicals, have zero porosity, and can be handled using clean-
8 room protocols, and are therefore amenable to system
9 integration using standard microelectronics fabrication
10 processes. Valves, sensors, and actuators could also be
11 fabricated using photostructurable glass ceramic materials with
12 applied metal or polysilicon layers to provide electrodes or
13 resistive structures for sensing and actuation.

14
15 A satellite can be made primarily of photostructurable
16 glass ceramic materials with supported electronic, electrical,
17 photonic, and MEMS devices. Spacecraft photonics and
18 electronics are preferably integrated onto and encapsulated by
19 glass ceramic substrates that multifunction as circuit boards.
20 The encapsulation provides limited prevention of contamination.
21 For example, a stack of integrated glass ceramic substrates can
22 multifunction as a support structure while providing interface
23 layers on which and through which are deposited conducting
24 interconnects for forming an electrical communications grid
25 about the support structure, and while providing internal
26 optical paths for optical communication between optical
27 transceivers for forming an optical communications grid about
28 the support structure. Optical communications between and

1 through the glass ceramic substrates of the support structure
2 is enabled due to the wide transparency range of the glass
3 phase of the photostructurable glass ceramic materials.
4 Specific regions and volumes of the support structure are
5 converted into the ceramic phase to provide enhanced dielectric
6 properties for microwave circuits or to provide additional
7 strength, while other regions and volumes are converted into
8 the glass phase to provide enhanced internal optical
9 communications.

10
11 The spacecraft thermal control for a glass ceramic
12 satellite is very different from a silicon or metallic
13 satellite. Photostructurable glass ceramic materials can have a
14 low thermal conductivity of 1.35 W/m-K for the glass phase
15 which is less than stainless steel or aluminum used in
16 conventional spacecraft. Due to the optical and near infrared
17 transparency of the photostructurable glass ceramic materials,
18 less than ten percent of received solar energy will be absorbed
19 in the material while almost all of the infrared energy from
20 the earth will be absorbed. This thermal absorption smoothes
21 the temperature ranges for a satellite in Earth orbit where a
22 significant fraction of the orbit is in eclipse. The high
23 thermal insulating aspects of photostructurable glass ceramic
24 materials can be thermally limiting for high power components,
25 such as microprocessors and communication circuits. Fabrication
26 of three-dimensional micro heat pipes, which are metalized and
27 help to direct the heat away from these sources, can mitigate
28 this thermal limitation of the photostructurable glass ceramic

1 materials. These and other advantages will become more apparent
2 from the following detailed description of the preferred
3 embodiment.

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Brief Description of the Drawings

Figure 1 is block diagram of a glass ceramic phone.

Figure 2 is block diagram of a glass ceramic spacecraft.

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Detailed Description of the Preferred Embodiment

An embodiment of the invention is described with reference to the figures using reference designations as shown in the figures. Referring to Figure 1, a glass ceramic phone, such as a cellular phone, can be adapted to include a variety of glass ceramic components in an all glass ceramic system. As used herein, a glass ceramic material is a material comprising glass or ceramic components, or both. A molded glass ceramic cover 10, a laser milled glass ceramic strut 12, and a laser milled glass ceramic base 14 form the structural components of the phone and collectively provide internal cavities for supporting encapsulated internal components. Internal to these structural components is a power converter 16 and a communications processor 18 connected together by horizontal interconnects 20. A thin film battery 22 is charged through an external power adapter 24 adapted for interface connection through a power cover feedthrough and a power base feedthrough 28 for connecting the power from the adapter 24 to the power converter 16. An internal antenna 29 is disposed in an antenna cover feedthrough 30 and an antenna base feedthrough 32 for transceiving telecommunications to the communications processor 18. The antenna can be a conductor of a predetermined length to radiate RF energy. The antennas can be composed of patterned electrically conducting materials to optimize RF radiation. The antenna 29 can be metallic or semiconducting. Discreet antennas can be patterned in the glass and ceramic materials using direct-write laser patterning or photolithographic techniques.

1 Laser-patterning can provide complex three-dimensional
2 structures such as a helical coil. When the glass and ceramic
3 material has a high metal dopant concentration, the helical
4 shape can be an embedded conductor to function as an antenna.
5 When the material does not have the added dopant, the exposed
6 material is then baked and etched to remove material to make a
7 hollow helical structure which is then back filled with a
8 conducting material.

9
10 Vertical interconnects 34 extend from the power converter
11 16 through vertical interconnect feedthrough 36 for
12 distributing power and control signals. The feedthrough 36 is a
13 channel or via that encapsulates a conductor. The interconnects
14 34 provide connectivity for RF and electrical signal in the
15 vertical direction. Molded shape glass ceramic cover 10 is
16 first molded to have appropriate overall design and then
17 patterned to have optical feedthroughs or transparency for the
18 transmission of optical signal and have acoustic feedthroughs
19 for transmission of acoustic energy. The cover 10 protects the
20 interior from the outside environment while providing an
21 ergonomic shape for handling. The cover 10 protects the
22 interior against contamination of dust, dirt, water, and
23 chemicals when baked and tempered into the ceramic state. The
24 glass ceramic materials, such as Foturan, can be first shaped
25 with a mold in an oven at 300°C to 460°C. The cooled shaped
26 molded component is then transferred to a direct-write UV laser
27 or UV light photolithography machine to expose areas to be
28 removed. The molded component is then rebaked using a second

1 baking cycle up to 600°C maximum and then etched in about 5%
2 hydrofluoric acid bath that is nominally at room temperature.
3 The previously exposed regions are etched away. The sample is
4 then baked a third time in an annealing oven of 300°C to 500°C
5 to make optical paths more transparent. The cover 10 houses all
6 the internal components providing IR, acoustic, and visual
7 transparency, as well as electrical feedthroughs. The strut 12
8 provides mechanical support, visually clear in the glass state,
9 that is an insulator at DC but also a very poor electrical
10 conductor at high frequencies. A laser, preferably an ultrafast
11 laser, such as a picosecond or femtosecond pulse width laser,
12 is used to ablate and mill the glass to shape. Depending on
13 whether the final structure is to be more like a ceramic or
14 more like a glass, the milled structure is volumetrically
15 exposed with UV light and baked to over 700°C to become a
16 ceramic, or simply baked at 500°C followed by a rapid cool down
17 in an oven to be tempered glass. The strut can function as an
18 electrical substrate for electronic components while providing
19 mechanical support and high optical transmission in the visible
20 and IR for internal optical free-space communications. The base
21 14 provides additional support but has integral feed through
22 vias for electrical and RF components. Via processing is also
23 done using UV light patterned exposure, but can then be
24 backfilled with conducting solid, paste, or gas, and then
25 heated to make integral conducting vias. The base 14 is an
26 electrical substrate for electronic components while providing
27 mechanical support and high optical transmission in the visible
28

1 and IR for optical free-space communications. The cover 10,
2 strut 12, and base 14 form a glass ceramic support structure.

3
4 The power converter 16 converts one voltage to another as
5 required by encapsulated electronic components. An electronic
6 power converter circuit, preferably an integrated circuit, is
7 disposed on the base 14. A recess, not shown, can be made in
8 the base for securely mounting the power converter 16. The
9 computer processor chip 18 controls the communication system
10 through optical radiation or RF communications. A processor
11 chip is preferably mounted in a recess made, not shown, in the
12 glass and ceramic base 14. The communications processor 18 can
13 be an RF integrated circuit or a multichip module with an RF
14 coplanar waveguide, not shown, made in the substrate base 14.
15 For an optical communications processor chip, the base 18 can
16 be annealed to improve transparency for passing optical
17 signals. The horizontal interconnects 20 are used for
18 communicating electrical or RF energy on a horizontal plane
19 between electrical and RF components. The interconnects can be
20 a thin film conductor, but could also be a coated waveguide or
21 a co-planar waveguide for high frequency through microwave
22 frequency applications greater than 10GHz. There are several
23 techniques for patterning electrical conductors onto or into
24 glass ceramic materials, including conventional standard
25 microelectronics processing such as patterned sputtering, laser
26 ablation and laser forward transfer process that deposits metal
27 from a metalized ribbon, laser annealing following a direct
28 write ink paste pen where the paste has conducting material, or

1 glass and ceramic material doping with a high concentration of
2 metal atoms where a laser is used to form thin metalized lines
3 within the glass by laser coagulation of metal. For the RF
4 communication where the interconnects 20 comprise waveguides,
5 trenches are laser milled using the variable laser exposure
6 technique followed by a bake and etch for where the material is
7 to be removed. The trench is then coated with metal to function
8 as a waveguide. The horizontal interconnects provide conduits
9 for electrical and RF energy flow and communications about the
10 integrated glass ceramic system. Thin film batteries provide
11 local and distributed power to the encapsulated electrical
12 devices. Thin film batteries can be made by laser ablation and
13 depositing multiple materials using a patterning method by
14 sputtering multiple layer of battery compounds through masks.
15 The power adapter 24 permits charging of the battery 22 from an
16 electrical outlet. The adapter can be a direct wire plug
17 connector as shown, but because the integrated system can be
18 made to be transparent to visible and IR light, the system
19 could be powered by solar or other light power sources. The
20 power cover feedthrough 26 enables the transfer of energy from
21 an outside electrical power source to charge batteries as well
22 as protecting inside components from contamination. For an
23 optical power line, the system can be powered by a directed
24 beam source, such as a laser. To fabricate an optical power
25 adapter, a laser is used to create waveguides. An ultra fast
26 laser is used to expose the material which is then baked at
27 less than 500C to create an index of refraction change that
28 will guide laser light through the glass and ceramic material.

1 The power base feedthrough 28 is mated to the power cover
2 feedthrough 26 either by direct electrical contact or by
3 proximity contact for optical power transfer. As such, the
4 integrated system has a power adapter and power storage
5 elements for use with an electrical grid for power components
6 distributed within the integrated glass ceramic system.

7
8 A received optical image 38, such as a terahertz or
9 millimeter wave image, is received through an optical image
10 lens 40, communicated through a portion of the molded cover,
11 and received by an optical terahertz or millimeter wave image
12 sensor 42, such as CCD camera, CMOS photosensor chip,
13 microbolometer array, or a direct deposited thin film
14 photosensor that converts light into electrical signals for
15 receiving the received optical terahertz or millimeter wave
16 image 38, such as a still image when the CCD camera operates as
17 a still image camera. Light can be modulated or unmodulated,
18 such as an unmodulated image or a modulated IR beam with
19 encoded information. There are several approaches to make a
20 lens. A diffractive lens is made by using a laser to laser mill
21 or to expose followed by a bake and etch process to generate
22 circular grooves of appropriate diameter, kerf width, and
23 pitch, after the material has been removed. The lens is baked a
24 second time to smooth out the kerf for making a diffractive
25 planar lens that will focus onto the image sensor 42. Another
26 approach is to create annular regions of metastable or ceramic
27 material using a UV laser exposure followed by a bake cycle.
28 The exposed portion will expand by a few percent and push clear

1 glass within the annulus to create a convex surface, which will
2 focus optical, terahertz, or millimeter wave optical signals
3 below, Another approach is to use laser milling to shape a lens
4 of any shape by directly removing material. The milled material
5 is then baked for annealing and minor surface defect removal.

6
7 A transmitted optical image 44 is transmitted through a
8 transmitter optical image lens 46 and originates from an
9 optical display 48 for transmitted or displaying the
10 transmitted optical image 44. The glass ceramic material
11 between the display 48 and the outside is annealed to insure
12 high-resolution low-loss optical transmission through the
13 support structure. The lens 40 serves to focus incoming light
14 onto a photosensor for efficient energy coupling. The display
15 can be a typical cell phone readout, such as displaying a
16 currently called telephone number and elapsed time of a
17 conversation. The device can be make to communicate optical
18 signals through the glass ceramic materials. The display can be
19 an optical emitter with light passing through the glass ceramic
20 material in the glass state. The glass and ceramic material in
21 the glass state provides a vertical path to communicate optical
22 signals or to transfer power.

23
24 A received audio signal 50 is received through received
25 audio apertures 52 and sensed by an audio microphone processor
26 54 for receiving an audio signal such as a voice audio signal
27 occurring during a typical telephone conversation. The audio
28 signal could be encoded with digital information for

1 information transfer. The audio apertures channel acoustic
2 energy and focuses the acoustic energy to an electrical audio
3 amplifier of the processor 54. Laser UV exposure and bake and
4 etching is used to shape the three-dimensional apertures 52.
5 Laser Milling can also be used to construct cylindrical via
6 holes. A transmitted audio signal 56 is transmitted through
7 transmitted audio apertures 58 and originates from an audio
8 speaker processor 60 having speakers for generating the
9 transmitted audio signal such as the reply conversation from a
10 phone user to which the glass ceramic phone is currently
11 communicating. Of course additional elements, such as a touch
12 tone key pad, not shown, can be incorporated, as well as other
13 desired buttons and controls.

14
15 The glass ceramic phone is characterized as having an all
16 glass ceramic structural supports that are molded, patterned,
17 or laser milled serving to internally encapsulate active
18 operational components while enabling internal optical
19 communications between the active components and physically
20 through a portion of the structural support. In the preferred
21 form, the converter 16, processors 18, battery 22, microphone
22 54, camera 42 and speakers 60 are all active components
23 encapsulated within the glass ceramic components 10, 12, and
24 14, with internal optical communications extending from the
25 display 48 to and including the lens 46, and through a portion
26 of the structural components, and particularly through a
27 portion of the molded cover 10. The upper molded cover 10 and
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1 lower base can be made of tempered glass for improved
2 structural strength about the exterior of the phone.

3
4 Referring to Figure 2, another example of an all glass
5 ceramic system is the glass ceramic spacecraft. The spacecraft
6 includes structural elements, such as a laser milled and molded
7 glass ceramic dome 80, a laser milled glass ceramic thruster
8 substrate 82, a laser milled glass ceramic sensor substrate 84,
9 a laser milled glass ceramic optical substrate 86, a laser
10 milled glass ceramic battery substrate 88, a laser milled glass
11 ceramic processor substrate 90, and a laser milled glass
12 ceramic antenna substrate 92. The dome 80 and substrates 82,
13 84, 86, 88, and 90 are bonded together to form a single all
14 glass ceramic rigidly-integrated support structure in which is
15 encapsulated many active and passive components and through
16 which is communicated optical signals. Laser patterning
17 composed of exposing, baking and etching, can also be used to
18 replace or augment laser milling.

19
20 The dome 80 is a molded glass ceramic component in that
21 molten glass is injected or poured, for examples, into a mold,
22 not shown, for providing the substantially curved inner and
23 outer surfaces of the dome 80. The dome 80 is shaped to
24 efficiently serve as a pressure tank and a radome while
25 providing feedthroughs for power and RF signals. The dome 80
26 provides a three-dimensional structure for mounting antennas, a
27 radome for external or embedded antennas, and a pressure
28 containment system. The convex shape also enables wide beam-

1 pointing angles for phased array antennas, or the use of
2 multiple antennas pointing in different directions. The glass
3 and ceramic material, such as Foturan, is first shaped with a
4 mold in an oven at 300°C to 460°C, then cooled and transferred
5 to a UV laser or UV light lithography machine to expose areas
6 to be removed. The molded shape is then rebaked to 600°C maximum
7 and then etched in about 5% hydrofluoric acid bath nominally at
8 room temperature. The exposed regions are etched away. The
9 sample is then baked a third time in an annealing oven from
10 300°C to 500°C to make the optical paths more transparent.

11

12 The thruster substrate 82 has shaped channels that guide
13 gas, fluid, or particle flow in either subsonic or supersonic
14 flow to thrusters or pneumatic components. The thruster
15 substrate 82 also provides structural support. The thruster
16 substrate 82 can be milled with an ultrafast picosecond or
17 femtosecond pulse width laser to efficiently ablate the glass
18 with very high precision. The laser beam is directed across the
19 substrate surface using CAD/CAM control software. The thruster
20 substrate 82 can be made by etching when nozzle shapes and
21 fluid channels are fabricated in the material by direct-write
22 UV laser patterning or UV photolithography. The material is
23 then baked at a maximum temperature of 600°C and then etched in
24 about 5% hydrofluoric acid to remove the exposed regions. The
25 channels and nozzles can be fabricated on the top or bottom
26 surface using either the UV photolithographic or UV direct-
27 write laser approach. Embedded channels can be made using the
28 direct-write approach when the laser is focused within the

1 substrate and the beam dose is controlled so that it only
2 exposes the material in the focal volume region where the laser
3 beam comes to a focus.

4
5 The sensor substrate 84 serves as a holder for electrical
6 die and components and can be a multichip module substrate that
7 also functions as part of the spacecraft support structure.
8 Power and data are routed via electrical feedthroughs and
9 optical paths among the sensors, actuators, and control
10 processors. A layout and interconnection pattern is first
11 generated, and a surface topography pattern is created based on
12 component layout on the surface and individual component
13 heights. Recesses of various depths can be used to provide
14 cleared volumes for various components between the sandwiched
15 glass and ceramic substrates. The glass and ceramic material is
16 patterned by UV laser direct-write exposure and baked and
17 etched while an ultrafast laser is used to pattern sections
18 that have to be milled and cannot be baked and etched. When the
19 material is to be etched, it is first baked then etched. When
20 milled, the material can annealed by baking using a low
21 temperature bake cycle of less than 450°C. The die and
22 supporting components are placed into the recesses in the
23 substrate. Solder bump or other space-qualified component
24 interconnect technology such as conductive epoxies can be used
25 to affix the die and other components in the recesses of the
26 substrate. Interconnecting lines for conducting electrical
27 signal can be patterned. When the interconnect is for an
28 optical emitter, then no processing is required as the glass

1 will pass the light, When the interconnect is for RF or
2 electrical feedthrough interconnection, then there are several
3 techniques for patterning electrical conductors onto glass and
4 ceramic materials. Conventional photolithographic patterning
5 of a deposited layer, laser ablation and material forward
6 transfer processing, laser annealing following a direct-write
7 ink paste pen where the paste contains conducting material,
8 doping glass ceramic material with a high concentration of
9 metal atoms where a laser is used to form thin metalized lines
10 within the glass by metal precipitation, or laser or
11 photolithographic patterning of the surface followed by
12 conductor deposition and chemical and mechanical polishing to
13 leave conductive trenches, can be used. For RF waveguides,
14 trenches can be made using the variable laser exposure
15 technique to expose and bake and etch the material where
16 materials are to be removed. The trench is then coated with
17 metal. The sensor substrate serves as a complex multilayer
18 electronic and photonic substrate that also provides structure
19 and thermal heat-sinking of sensor components.

20
21 The optical substrate 86 supports optical processing
22 components. Recesses are formed in the substrate for optical
23 processing devices. Optical waveguides that direct the light
24 beam to a particular direction or free-space transmission
25 regions where a light beam is directed within the glass, are
26 then patterned, For the waveguides, an ultrafast laser with low
27 power is used to expose the glass locally in the pattern of the
28 waveguide shape with vertical lines and horizontal lines. The

1 glass is then baked so that it partially crystallizes at less
2 than 600°C that causes a change in the index that is sufficient
3 to guide red light or IR light over many centimeters. Free-
4 space communication in the glass ceramic material is also
5 possible in the visible or IR. Where it is necessary to change
6 the direction of the laser beam, a slot is cut either by laser
7 milling or by UV exposure and bake and etch. The resulting slot
8 is then annealed slowly at less than 500° C to smooth the slot-
9 walls to sub-micron flatness. The slot-walls with an air gap
10 then become internally-reflecting mirrors within the optical
11 substrate to direct the light traveling within the glass to the
12 appropriate sensor, detector, or power absorber. The optical
13 substrate provides optical paths and processing devices for
14 optical communications and optical power transfer throughout
15 the substrate without the use of conducting vias.

16
17 The battery substrate 88 serves as part of the spacecraft
18 support structure, and as a holder for batteries, and contains
19 electrical vias for DC power connections to other layers. The
20 substrate also has recesses and vias for receiving and
21 distributing electrical power. The substrate 88 provides
22 support structure, thermal heat-sinking of components,
23 containment of batteries, and electrical interconnects between
24 the batteries and the spacecraft power bus. The processor
25 substrate 90 serves as part of the spacecraft support
26 structure, a thermal heat sink for electronics, and as an
27 interconnect system for spacecraft processors and associated
28 electronics. It contains electrical vias for DC power

1 connections to other layers. The substrate 90 is made with
2 recesses and vias. The antenna substrate 92 serves as part of
3 the spacecraft support structure, an interconnect system
4 between antennas and RF electronics, and an antenna support.
5 The substrate 92 contains RF vias and cutouts to support
6 various antenna configurations such as patch antennas. The
7 substrate 92 is part of the support structure and a thermal
8 heat-sink for electrical components, and provides electrical
9 interconnects between the spacecraft RF communications system
10 and various antennas.

11
12 The top surface of the dome 80 can be laser milled or
13 laser exposed, baked, and etched, for providing a star tracker
14 cavity 95 into which is received a star tracker image 94 that
15 passes into the star tracker cavity 95 and through a star
16 tracker lens 96 to a star tracker imaging processor 97. The
17 cavity 95 can be open space or a glass ceramic insert. The dome
18 80 is further laser milled or laser exposed, baked, and etched,
19 to provide a plurality of phased array antenna feeds 98 and
20 respective phased array antenna dishes 100 distributed over the
21 outer surface of the dome in a conventional phased array
22 configuration. The star tracker image 94 is the optical
23 wavefront pattern of visible emitters in the universe, as a
24 stream of photons from optically-emitting bodies in space, such
25 as stars, planets, moons, and nebulae. The optical image 94
26 provides orientation information for the spacecraft. The star
27 tracker lens 96 is used to focus incoming photons from the
28 various light-emitting bodies in the universe onto an image

1 detector for determining spacecraft attitude. The lens 96 can
2 be any optically-transparent material, including glass ceramic
3 materials, that have the correct shape and refractive index to
4 focus parallel light rays from a source at infinity onto a
5 detector array. Transparency to visible radiation is normally
6 required, but can be extended to UV, X-ray, or IR terahertz or
7 millimeter wavelengths as needed. The lens focuses incoming
8 electromagnetic energy onto an image detector. The star tracker
9 imaging processor 97 includes a star tracker image detector.
10 The star tracker imaging processor 97 processes output signals
11 from the star tracker image detector and calculates spacecraft
12 orientation. The processor 97 is preferably a digital processor
13 that runs algorithms to first determine what part of the sky
14 the sensor is seeing, and then determines the spacecraft
15 orientation. Normally, only relative star positions on the
16 image detector are used to determine spacecraft orientation.
17 The star tracker imaging processor 97 takes raw image data from
18 the star tracker imaging detector and provides a digital output
19 with spacecraft orientation information to the spacecraft
20 central processor 182. The phased array antenna feed network 98
21 includes antennas feeds at the correct phase to provide the
22 desired phased array antenna gain pattern. The phased array
23 antenna network 98 can have passive structures to provide a
24 fixed antenna pattern, or it can provide controllable phases
25 and amplitudes to various antennas to generate various antenna
26 beam angles and beamwidths. The phased array antenna network 98
27 can be a patterned conductive layer deposited on the glass and
28 ceramic substrate radome 80. The phased array antenna network

1 98 feeds and dishes 100 may also contain active components such
2 as amplifiers, RF switches, phase shifters, and attenuators for
3 antenna operation. The antenna dishes 100 have recesses that
4 can be laser milled or laser exposed, baked, and etched after
5 molding, or can be formed during the molding process.
6 Deposition and patterning of the conducting layer can be
7 performed before or after molding. Ductile conductors can be
8 applied before molding, brittle conductors can be applied after
9 molding, and metal doping can occur before or after molding.
10 The phased array antenna feed network 98 is used to coherently
11 combine signals from multiple antennas to provide the required
12 antenna gain properties such as gain, beamwidth, and beam
13 direction. The phased array antenna dishes 100 couple RF
14 radiation between antenna feeds and free-space. Antennas feeds
15 98 and dishes 100 can have conductors in various
16 configurations, such as for dipole antennas, dipole coupled
17 with RF reflectors, quarter-wave antennas coupled to parabolic
18 dishes, or simple conductors coupled with dielectric focussing
19 elements, such as lenses. The antenna system includes the
20 phased array network 98 and dishes 100 provide a desirable
21 antenna gain pattern for spacecraft communications, radar, RF,
22 and microwave power beaming, or remote sensing. The fuel
23 reservoir 102 provides propellant storage volume for the
24 spacecraft. As should now be apparent, the integrated dome 80
25 serves as a star tracker support, a phased array antenna
26 support, a reservoir for propellant, as well as a glass ceramic
27 integrated support for the entire spacecraft. The dishes 100
28

1 can be made by laser milling the molded dome, or by UV laser
2 patterning, baking and etching.

3
4
5 The dome 80 is further used for defining a fuel reservoir
6 102 containing a propellant for thrusting the spacecraft using
7 a right fuel control valve 104 and a left fuel control valve
8 106. The left valve 106 is used to control fuel flow into a
9 left thruster plenum 108 and out a left thruster nozzle 110.
10 The right valve 104 is used to control fuel flow into a right
11 thruster plenum 112 and out a right thruster nozzle 114. The
12 fuel reservoir 102 is formed by the molding. The fuel reservoir
13 102 contains propellant that will travel through the propellant
14 feed lines and into the plenums 108 and 112 of the thrusters.
15 The right and left fuel control valves 104 and 106 modulate the
16 flow of propellant from the reservoir 102 to one of the
17 thrusters. The valves 104 and 106 provide modulated fuel flow
18 restrictions, The flow restriction can be modulated using
19 magnetic force, such as by solenoid valves, pneumatic pressure
20 such as by hydraulic valves, and electric force such as by
21 electrostatic MEMS valves, piezoelectric force by piezoelectric
22 materials, or thermally-generated mechanical force by bimorph
23 actuators or by material expansion and freezing. The valves
24 104 and 106 are disposed into a propellant cavity 102. The
25 valves 104 and 106 can be on and off valves or metering valves
26 to provide variable flow rates and hence variable thrusts. The
27 left and right thruster plenums 108 and 112 are used to provide
28 a propellant cavity upstream of the thruster nozzles 110 and

1 114. The plenum cavities 112 and 108 have a larger diameter
2 than the propellant feed line, and the linear propellant speed
3 through the plenum is smaller than the linear speed through the
4 propellant feed line. Reduced propellant speeds upstream of the
5 nozzle improve thruster efficiency. In bipropellant thrusters,
6 reacting chemicals are typically brought together in the low-
7 velocity plenum to create a high temperature gas. In
8 electrothermal thrusters, heat is added by resistors, arcs, or
9 RF power. The plenums 112 and 108 connect a propellant feed
10 line to a thruster nozzle with high efficiency. The left and
11 right thruster nozzles 110 and 114 convert propellant enthalpy
12 heat energy into directed kinetic energy thrust, The nozzles
13 114 and 110 include a converging section with decreasing cross
14 section along the flow direction followed by a diverging
15 section with increasing cross section along the flow direction.
16 The flow accelerates in the converging section until it reaches
17 sonic velocity at which point a diverging section serves to
18 further accelerate the supersonic flow.

19
20 The left control valve 106 and the right valve 104 receive
21 power through vertical power interconnects 116 extending
22 through a vertical power feedthrough 117 that passes through
23 substrates 90, 88, 86, 84, 82, and dome 80. The vertical
24 electrical interconnects 116 in the feedthrough 117 provide
25 electrical connections. The interconnects 116 and feedthrough
26 117 allow DC power and electrical signals to be distributed.
27 The interconnects 116 can be spring-loaded electric
28 interconnects fabricated on the glass ceramic substrate, or

1 metallic pads fabricated on an undercut substrate which uses a
2 glass ceramic spring that is a straight or curved beam that
3 has compliance normal to the substrate surface. The
4 interconnects 116 connect various components in respective
5 substrates together and provides an external attachment point
6 for connecting the spacecraft to power sources and test
7 equipment. These attachment points can be used for ground-based
8 tests and for monitoring the spacecraft on the launch vehicle.
9

10 The left valve 106 receives left optical control signal
11 through an left vertical optical path 118 and receives power
12 through a left control valve feedthrough 120. The right valve
13 104 receives right optical control signal through a right
14 vertical optical path 122 and receives power through a right
15 control valve feedthrough 124. A top horizontal communications
16 interconnects 123 extend from vertical interconnects 116 so as
17 to route power to the valves 104 and 106. Left and right
18 control valve feedthroughs 120 and 124 contain an electrical
19 conductor that passes through the glass ceramic substrate 82.
20 The feedthroughs 120 and 124 provide power and control signals
21 to the left and right control valves 106 and 104. The optical
22 paths 118 and 122 and feedthroughs 120 and 124 serve to provide
23 power and control signals to the valves 104 and 106 for
24 providing control thrust from the opposing nozzles 114 and 110,
25 respectively. The vertical optical paths 118 and 122 enable
26 photons to travel through the substrates to the valves 106 and
27 104 for thruster control. The photons travel in straight-line
28 free-space paths can be processed by photonic devices, such as

1 reflectors, absorbers, or diffracting elements, The photons can
2 also travel in optical waveguides. The plenums 108 and 112,
3 nozzles 110 and 114, feedthroughs 117, 120 and 124 can be made
4 by laser milling the thruster substrate 82, or by laser
5 patterning, baking, and etching.

6
7 A variety of sensors may be disposed in the sensor
8 substrate 84. The sensor substrates includes a gyro sensor
9 cavity 126 in which is disposed a gyro sensor 128. A passive
10 sensor cavity 130 in which is disposed a passive sensor 132
11 comprising an optical transceiver communicating over a passive
12 optical path 134. An active sensor cavity 138 in which is
13 disposed an active sensor 136 has an exemplar optical
14 transceiver 140 communicating over an active sensor optical
15 path 142. The gyro sensor cavity 126 is a cavity that contains
16 a gyro or rate gyro that is a gyro sensor 128. The gyro sensor
17 or rate gyro sensors 128 uses a rotating mass or vibrating mass
18 to provide an inertial frame of reference. Changes in rotation
19 or vibration of the mass indicate a change in orientation. The
20 gyro sensor 128 may be a conventional gyro or a MEMS gyro
21 fabricated directly in the glass ceramic substrate 84. The gyro
22 or rate gyro 128 provides information on the either current
23 orientation, or current angular rates-of-change from a
24 previously known initial orientation and rotation rate. The
25 horizontal electrical interconnects 123 is used to communicate
26 signal from the gyro 128 as well as drive and feedback signals
27 from the valves 104 and 106, for interconnection to the
28 interconnects 116 as part of the electrical distribution grid.

1 The gyro sensor 128 communicates with the central processor 182
2 to provide current orientation information, or current angular
3 rates-of-change, from a previously known initial orientation
4 and rotation rate. The passive sensor 132 is disposed in the
5 passive sensor cavity 130. The passive sensor 132 modulates an
6 optical beam 134, to provide data on temperature, vibration,
7 pressure, or magnetic field. The passive sensor does not
8 consume power, but it reflects incoming light. Information can
9 be superimposed on the reflected light as an amplitude, phase,
10 or beam angle modulation. Pressure can be sensed by the
11 mechanical deformation of a thin diaphragm that is coated with
12 a reflecting material. The returned light will be deflected in
13 angle. A cantilever beam of sandwiched bimorph materials can
14 cause a similar deflection of angle as temperature changes.
15 Magnetic fields can be sensed using an optically-reflective
16 ferromagnetic coating on the end of a cantilever beam, Bragg
17 gratings, used in fiber optic sensors, can be fabricated in the
18 glass ceramic material to provide stress information. The Bragg
19 grating can be fabricated along a top or bottom layer surface
20 using narrow channels cut using either laser milling or UV-
21 exposed using laser or photolithographic chemical etching. The
22 passive sensor 132 requires an optical input beam and a
23 reflected light receiver, such as optical transceiver 186 which
24 may be part of the communications processor 172. The passive
25 optical sensor path 134 is the path that the incident and
26 reflected light takes within the glass and ceramic support
27 structure. The light travels in straight-line free-space paths
28 unless encountering internally-reflecting components such as

1 reflector 152, absorbers, diffracting elements, or other
2 photonic devices, such as an optical waveguide. The optical
3 path 134 connects optical sources, sensors, and transceivers.
4

5 The active sensor 136 produces an analog or digital output
6 in response to voltage, current, or an environmental condition
7 such as stress, temperature, pressure, or magnetic field. The
8 active sensor 136 is an integrated circuit, module, or
9 component. The sensor 136 provide environmental and spacecraft
10 health data to the central processor 182. The active sensor 136
11 is disposed in the cavity 138 within the glass ceramic
12 substrate 84. A sensor optical transceiver 140 generates
13 photons and contains a photo detector to detect incoming
14 photons. The photon generator can be a light emitting diode, a
15 diode laser, gas discharge, or a hot filament. The photon
16 detector can be a single detector, a linear array, or a two-
17 dimensional detector to provide angle detection capability. The
18 optical transceiver 140 can includes a number of components
19 such as diode lasers and CMOS image sensors integrated together
20 on a common substrate, or disposed on the glass ceramic
21 substrate 84. Wavelength dispersing elements can be fabricated
22 in the glass ceramic substrate 84 for improved optical
23 communications. The sensor optical path 142 passes optical
24 signals from the active sensor 136, passive sensor 132, and the
25 optical transceiver 140. The optical signals travel in path 142
26 through the glass ceramic substrates 84, 86, 88 and 90 as part
27 of an optical communication grid having straight-line free-
28

1 space paths, or reflected and diffracted paths, or optical
2 waveguides.

3
4 A variety of photonic devices, such as optical splitters,
5 filters, polarizers, fibers, lenses, and like optical means may
6 be disposed in an optical substrate 86. The exemplar optical
7 substrate includes a passive sensor beam splitter cavity 144, a
8 left beam splitter cavity 146, a right beam splitter cavity
9 148, and an active sensor beam splitter cavity 150. The passive
10 beam splitter cavities 144, 146, 148, and 150 can be a
11 triangular trench 152, 154, 156, and 158 in the glass ceramic
12 substrate 86 to create optical beam splitters, or photonic
13 devices 152, 154, 156, and 158 can be air gap slots cut at a
14 desired angle. These beam splitters connect to the optical path
15 160 which is a horizontal optical data bus as part of the
16 optical communications grid. The passive sensor beam splitter
17 cavity 144 supports a passive sensor beam splitter 152. The
18 left beam splitter cavity 146 supports a left beam splitter
19 154. The right beam splitter cavity 148 supports a right beam
20 splitter 156. The active sensor beam splitter cavity 150
21 supports an active sensor beam splitter 158. In the preferred
22 form, a horizontal optical path 160 extends through each of the
23 beam splitters for interconnecting optical paths 134, 118, 122,
24 and 142. The horizontal optical path 160 also extends through
25 an optical fiber 162 and an optical fiber lens 163 for external
26 optical communication suitable for communications with another
27 spacecraft or host craft in which the glass ceramic spacecraft
28 may be stowed. The optical communication grid can include an

1 optical fiber 162 and lens 163 for optical communications with
2 an external optical system, not shown. The optical fiber 162 is
3 a waveguide for UV, visible, or IR photons. The fiber 162 is
4 usually a cladde glass or plastic fiber that can also be
5 fabricated in the glass ceramic material. The lens 163
6 efficiently couples light between optical transceivers, optical
7 fibers, and free-space. The lens 163 is used to focus and
8 couple free-space photons into or out of the optical fiber 162.
9 The lens 163 is usually a glass or plastic lens, but can also
10 be fabricated in the glass ceramic substrate 86.

11
12 The battery substrate 88 includes a battery cavity 168 in
13 which is disposed a right battery 164 and a left battery 166.
14 The battery substrate is bonded to the processor substrate 90
15 that provides power for charging the batteries 164 and 166
16 during solar sunlight exposure or that receives power from the
17 battery during solar eclipses. The right and left batteries 164
18 and 166 disposed in the battery cavity 168 store electric
19 energy as chemical energy. Multiple batteries in series provide
20 an output voltage that is an integral number of the cell
21 voltage. Power feedthrough 169 serves to conduct electrical
22 power lines to and from the batteries 164 and 166.

23
24 The processor substrate 90 includes a communications
25 processor cavity 170 in which is disposed a communications
26 processor 172 having a built in optical transceiver for optical
27 communications along optical path 134, includes a power
28 converter cavity 174 in which is disposed a power converter,

1 and includes a central processor cavity 178 in which is
2 disposed an exemplar metal hybrid can 180 that encloses a
3 central processor 182 and an RF transceiver 184 and in which is
4 disposed a central processor optical transceiver 186 for
5 optical communications along optical path 142. The glass
6 ceramic substrate provides mechanical structure and thermal
7 control for electronic devices. The communications processor
8 172 includes RF transceivers coupled with digital central
9 processor 182 and provides spacecraft communications with the
10 outside universe for commands, telemetry transmission, and
11 payload data transmission. The power converter cavity 174 is a
12 cavity in the glass ceramic substrate 90 that houses the power
13 converter 176. The glass ceramic substrate 90 provides thermal
14 control and support for the power converter 176. The power
15 converter 176 is an electronic circuit that takes one input
16 voltage and produces one or more different output voltages for
17 various spacecraft functions. The power converter 176 receives
18 output voltages from left and right solar cell panels 194 and
19 196 for charging the spacecraft batteries and operating various
20 devices distributed about the spacecraft through the electrical
21 communications grid. A central processor cavity 178 houses the
22 hybrid 180 including the central processor 182 and the RF
23 transceiver 184. The cavity 178 in the glass ceramic substrate
24 provides support and thermal control. The hybrid metal 180 has
25 a conducting surface for RF shielding for internal components
26 182 and 184. The conducting coating can also be applied to the
27 cavity 178. The central processor 182 is a digital integrated
28 circuit that provides central control to operate the

1 spacecraft. The central processor 182 receives commands from
2 the RF transceiver 184, operates the various spacecraft
3 systems, and formats data for transmission to the ground. The
4 RF transceiver 184 is an RF circuit that receives signals from
5 within the spacecraft, amplifies the incoming signals, and
6 translates them to a lower frequency where digital circuitry
7 can extract data from phase or amplitude information. The
8 circuit 184 also receives digital data from the processor 182
9 and modulates an RF output for transmission to other RF
10 transceivers and devices within the spacecraft as part of the
11 electrical communications grid. The optical transceiver 186
12 generates photons and contains a photo detector to detect
13 incoming photons. The photon generator can be a light emitting
14 diode, a diode laser, a hot filament, or a gas discharge. The
15 photon detector can be a single detector, a linear array, or a
16 two-dimensional detector to provide angle detection capability.
17 The sensor optical transceiver 186 links various active and
18 passive optical sensors, and other optical transceivers, with
19 the central processor 182. The communications processor 172
20 links the passive optical sensors and other optical transceiver
21 with the central processor 182. The processor 172 also contains
22 RF circuitry for communications with the outside universe. The
23 passive optical sensors require a wavelength dispersing
24 element, such as a prism or diffraction grating. The wavelength
25 dispersing elements can be fabricated in the glass ceramic
26 substrate 90 as well.

1 The electrical interconnects 123 and 116 are further
2 interconnected to bottom horizontal communications interconnect
3 188 by vertical power and signal interconnects 116. The bottom
4 horizontal communications interconnects 188 include conductor
5 traces that provide power and data transfer between
6 communications and processor components. The bottom horizontal
7 communications interconnect links the communications processor
8 172, the power converter 176, the central processor 182, the RF
9 transceiver 184, and the central processor optical transceiver
10 186 with the remaining components of the system as part the
11 electrical communication grid. It is now apparent that the RF
12 transceiver 184 provides for RF communications within the
13 spacecraft. The optical transceiver of the communication
14 processor 172, the central processor optical transceiver 186,
15 active sensor optical transceiver 140, the fiber optics 162,
16 the fiber lens 163, and the beam splitters 152, 154, 156, and
17 158, as well as the glass ceramic substrates 82, 84, 86, 88,
18 and 90 provide an optical communications grid about the
19 spacecraft.

20
21 A right solar cell feedthrough 190 and a left solar cell
22 feedthrough 192 route power lines respectively from a right
23 solar cell panel 194 and from a left solar cell panel 196 to
24 the power converter 176 for collecting and distributing power
25 to charge the batteries 164 and 166 and to power other
26 electronic devices including the communications processor 172,
27 the central processor 182, RF transceiver 184, the active
28 sensor 136, the active sensor optical transceiver 140, and

1 valves 104 and 106. The operational devices of the spacecraft
2 include fluidic devices, such as valves, pumps, tubes, nozzles,
3 filters, among many others. The right and left solar cell
4 feedthroughs 190 and 192 are conductive traces that pass
5 through the glass ceramic substrate 92 for DC power transfer.
6 The right and left solar cell panels 194 and 196 may include
7 semiconductor p-n junctions that convert incoming solar light
8 into DC current at a predetermined voltage. The solar cell
9 panels are bonded to the substrate 92. Normally, solar panels
10 are bonded on the outside of the spacecraft. With transparent
11 glass structure, solar panels can be mounted inside the
12 spacecraft as the substrates can be light transmissive.
13 Electrical power and communication signals are also
14 communicated over interconnects 188 through an imager
15 feedthrough 198 to an imager 200 having an imaging lens 202.
16 Electrical power and communications signals are also
17 communicated over interconnects 188 through an attitude optical
18 sensor feedthrough 204 to an attitude optical sensor 206
19 having an attitude optical sensor lens 208. RF communications
20 signals are also communicated over interconnects 188 through a
21 patch antenna feedthrough 210 to a top patch antenna 212 and a
22 bottom patch antenna 214 for external RF communications. The
23 imager feedthrough 198 includes conductive traces that pass
24 through the glass ceramic substrate 92 to provide data transfer
25 along the interconnects 188. The imager feedthrough 198 takes
26 imager data from the imager 200 and transfers the imager data
27 to the central processor 182 through the bottom horizontal
28 communications interconnects 188. The imager 200 is an image

1 sensor including an integrated lens 202. The imager 200
2 provides Earth observation or spacecraft images for the central
3 processor 182. An attitude optical sensor feedthrough 204
4 includes conductive traces that pass through the glass ceramic
5 substrate 92 to provide data transfer. The attitude optical
6 sensor feedthrough 204 communicates attitude sensor data
7 through the bottom horizontal communications interconnect 188
8 to the central processor 182. The attitude optical sensor 206
9 may be a CCD, CMOS, or MEMS image sensor, coupled with a lens
10 208 that images the Earth, sun or stars. The imager attitude
11 information is based on the position of the sun, Earth, or
12 stars in the image. MEMS image sensors may be composed of
13 microbolometer sensor array fabricated on glass ceramic
14 substrate 92 using conventional semiconductor processing
15 techniques. The patch antenna feedthrough 210 includes
16 conducting traces and connects the patch antenna to the RF bus
17 of the interconnects 188. The feedthrough 210 enables patch
18 antennas communications. The patch antenna includes a top patch
19 antenna 212 and a bottom patch antenna 214. A conductive
20 pattern, located over a dielectric, but not touching a larger
21 conductive pattern below, can function as a flat patch antenna
22 with moderate gain. The patch antennas 212 and 212 can be used
23 as moderate-gain omnidirectional antennas for RF
24 communications.

25
26 It is now apparent that the spacecraft includes an
27 electrical communications grid comprising lines 116, 123, and
28 188 as well as electrical lines extending through feedthroughs

1 120, 124, 169, 117, 192, 190, 198, 204 and 210 for power
2 distribution and electrical digital and analog communications
3 about the ceramic spacecraft, as well as comprising any
4 internal RF communications. The electrical communications grid
5 also includes free-space RF transmissions within the
6 spacecraft. It is now equally apparent that the spacecraft
7 includes an optical grid of optical paths 118, 122, 134, 142,
8 and 160 horizontally and vertically extending through
9 substrates 82, 84, 86, 88, and 90 for communicating optical
10 signals about the spacecraft. That is, the electrical
11 interconnects using horizontal planar traces 123 and 128, and
12 feedthroughs 120, 124, 117, 190, 192, 198, 204 and 210
13 communicate electrical power and RF signals while the glass
14 ceramic structures 82, 84, 86, 88, and 90 through optical paths
15 118, 122, 134, 142, and 160 enable optical communications so as
16 to provide a comprehensive dual optical and electrical
17 communications network throughout the spacecraft.

18
19 The invention is directed to an integrated glass ceramic system
20 having a plurality of glass ceramic supports made from glass
21 ceramic materials integrated as a system support structure
22 including a communications network as an electrooptic
23 communications network having an electrical communications grid
24 and an optical communications grid. The glass ceramic material
25 include amorphous glass, ceramics, and composites of glass and
26 ceramics. In the preferred form, the glass ceramic materials
27 are photostructural glass ceramic materials having a
28 photosensitizing agent for photon exposure. The photon

1 exposures, such as UV laser exposure, is suitable for direct-
2 write patterning of features. The photon or laser exposures are
3 also suitable for localized ceramicization of a glass ceramic
4 support. The supports can be locally ceramicized, tempered or
5 anneal for improved strength. The support can be annealed for
6 improved internal optical communications along internal free-
7 space optical communications paths. Various glass and ceramic
8 materials can be used. Those skilled in the art can make
9 enhancements, improvements, and modifications to the invention,
10 and these enhancements, improvements, and modifications may
11 nonetheless fall within the spirit and scope of the following
12 claims.

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